

# Si CMOS ring resonator device for synthetic dimension photonics 合成次元フォトンクス用 Si CMOS リング共振器デバイス

Yokohama National University<sup>1</sup>, Tohoku University<sup>2</sup>, The University of Tokyo<sup>3</sup>, <sup>○</sup>Armandas Balčytis<sup>1</sup>,  
Tomoki Ozawa<sup>2</sup>, Yasutomo Ota<sup>3</sup>, Satoshi Iwamoto<sup>3</sup>, Jun Maeda<sup>1</sup> and Toshihiko Baba<sup>1</sup>  
横国大院工<sup>1</sup> 東北大学<sup>2</sup> 東京大学<sup>3</sup>, <sup>○</sup>バルチティス アルマンダス<sup>1</sup>, 小澤知己<sup>2</sup>, 太田泰友<sup>3</sup>,  
岩本敏<sup>3</sup>, 前田惇<sup>1</sup>, 馬場俊彦<sup>1</sup>

E-mail: armandas.balcytis@gmail.com

We present a synthetic frequency dimension on a Si CMOS ring resonator with a phase shifter modulator section, depicted in Fig. 1(a). It enables a fully integrated realization of effects previously demonstrated using a 13.5 m length fiber loop<sup>1)</sup>. Here, total ring circumference was  $l \approx 4.1$  mm to ensure a sufficiently small equidistant mode spacing, shown in Fig. 1(b). Most of the optical path proceeds via a 3- $\mu$ m-wide waveguide with 0.4 dB/cm expected loss, minimizing mode dissipation. As a result, ring quality factor was  $Q = 42,000$ , corresponding to a  $2\gamma = 4.5$  GHz photon decay rate. When the resonator is driven at its free-spectral range (FSR) rate of  $\Omega_R = 20.4$  GHz a frequency lattice spanning a 280 GHz bandwidth was established and sideband intensity enhancement was observed.

The synthetic dimension dispersion relations, plotted in Fig. 1(c-f), were acquired for the first time for a Si integrated photonic device by compiling 2D plots of time-resolved ring transmittance over a  $T = 50$  ps modulation period as a function of input laser detuning. Modulations at  $\Omega_R$  and  $2\Omega_R$  frequencies, corresponding to nearest- and second-nearest-neighbor coupled 1D tight-binding models, were employed. When both of these modulations are applied concurrently with different relative phases, a one-dimensional triangular ladder with an alternating magnetic flux can be simulated. Such coupling regimes can give rise to synthetic dimension band structures that are asymmetric around the  $k = 0$  point. Since in our synthetic frequency lattice the analog of the wavenumber  $k$  corresponds to time, this suggests the breaking of time-reversal symmetry and the onset of nontrivial topological effects<sup>2,3)</sup>.

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## References:

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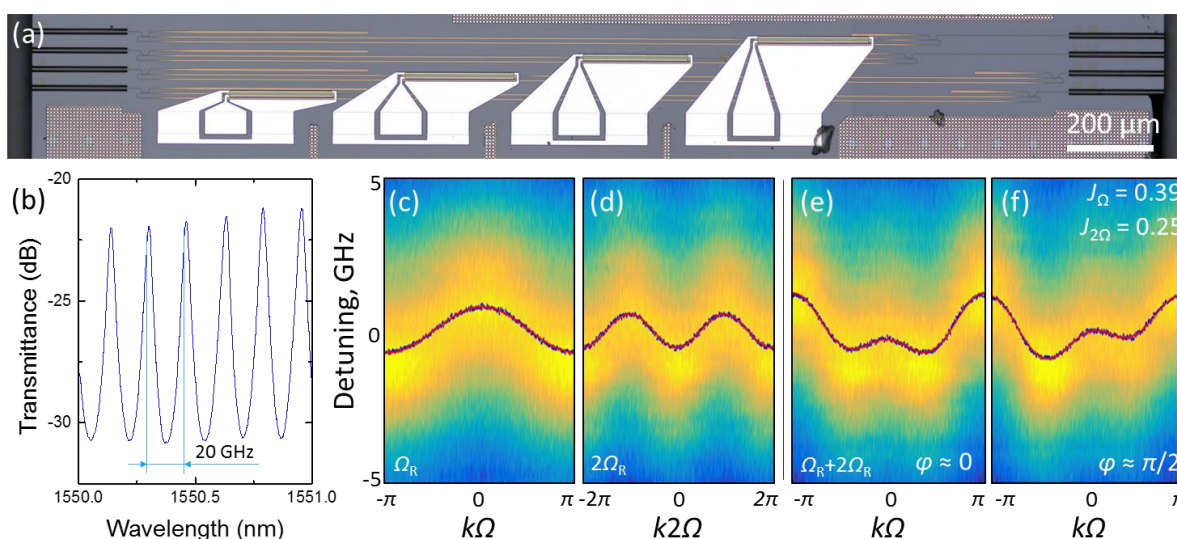


Fig. 1 (a) Micrograph of 4 modulator-equipped SOI ring resonators for synthetic frequency dimension. (b) Transmittance spectrum spanning 6 FSR (20 GHz) intervals. Synthetic frequency dimension bands at different on-resonance modulation regimes (c)  $\Omega_R = 20$  GHz, (d)  $2\Omega_R = 40$  GHz, (e,f) simultaneous  $\Omega_R$  and  $2\Omega_R$  with different relative phases. Solid lines are 1D tight-binding model  $\varepsilon_k = 2J_\Omega \cos(k\Omega + \phi) + 2J_{2\Omega} \cos k2\Omega$  fits.